

Vishay High Power Products

Phase Control Thyristors (Hockey PUK Version), 790 A

TO-200AC (B-PUK)

FEATURES

· Center amplifying gate



· Metal case with ceramic insulator

RoHS

• International standard case TO-200AC (B-PUK)

• Lead (Pb)-free

PRODUCT SUMMARY			
I _{T(AV)}	790 A		

TYPICAL APPLICATIONS

- DC motor control
- Controlled DC power supplies
- · AC controllers

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
		790	Α		
I _{T(AV)}	T _{hs}	55	°C		
1		1557	A		
I _{T(RMS)}	T _{hs}	25	°C		
	50 Hz	10 100	۸		
I _{TSM}	60 Hz	10 700	A		
l ² t	50 Hz	510	kA ² s		
-	60 Hz	475	KA-S		
V _{DRM} /V _{RRM}		2000 to 2400	V		
t _q	Typical	200	μs		
T _J		- 40 to 125	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA			
	20	2000	2100				
ST650CL	22	2200	2300	80			
	24	2400	2500				

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ST650C..L Series

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average on-state current		180° condu	180° conduction, half sine wave		790 (324)	Α
at heatsink temperature	$I_{T(AV)}$	Double side	(single side) co	poled	55 (85)	°C
Maximum RMS on-state current	I _{T(RMS)}	DC at 25 °C	heatsink tempe	erature double side cooled	1857	
		t = 10 ms	No voltage		10 100	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		10 700	Α
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		8600	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	9150	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage	initial $T_J = T_J$ maximum	510	kA ² s
		t = 8.3 ms	reapplied		475	
		t = 10 ms	100 % V _{RRM}		370	
		t = 8.3 ms	reapplied		347	
Maximum I²√t for fusing	I²√t	t = 0.1 to 10	t = 0.1 to 10 ms, no voltage reapplied			kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	(16.7 % x π x I _{T(AV)} < I < π x I _{T(AV)}), T _J = T _J maximum			V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			V
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x I _{T(AV)} < I < π x I _{T(AV)}), T _J = T _J maximum			0.61	
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.35	mΩ
Maximum on-state voltage	V_{TM}	$I_{pk} = 1700 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			2.07	V
Maximum holding current	I _H	T 25 °C	T 05 00 and a soul 40 V and that			mA
Typical latching current	ΙL	T _J = 25 °C, anode supply 12 V resistive load			1000	IIIA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	dI/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/μs
Typical delay time	t _d	Gate current 1 A, $dI_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}$, $T_J = 25 °C$	1.0	
Maximum turn-off time	t _q	I_{TM} = 750 A, T_J = T_J maximum, dI/dt = 60 A/μs V_R = 50, dV/dt = 20 V/μs, Gate 0 V 100 Ω , t_p = 500 μs	200	μs

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}	500	V/µs
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	80	mA



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TRIGGERING							
PARAMETER	CVMPOL	TEST SOUDITIONS			VALUES		
PARAMETER	SYMBOL	'-	ST CONDITIONS	TYP.	MAX.	UNITS	
Maximum peak gate power	P_{GM}	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	10	0.0	w	
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	VV	
Maximum peak positive gate current	I _{GM}			3	.0	Α	
Maximum peak positive gate voltage	+ V _{GM}	$T_J = T_J$ maximum,	$T_J = T_J$ maximum, $t_p \le 5$ ms			V	
Maximum peak negative gate voltage	- V _{GM}				.0		
DC gate current required to trigger		T _J = - 40 °C	Maximum required gate trigger/	200	-		
	I _{GT}	T _J = 25 °C		100	200	mA	
		T _J = 125 °C	current/voltage are the lowest	50	-		
		T _J = - 40 °C	value which will trigger all units	2.5	-		
DC gate voltage required to trigger	V_{GT}	T _J = 25 °C	12 V anode to cathode applied	1.8	3.0	V	
		T _J = 125 °C		1.1	-		
DC gate current not to trigger	I _{GD}	T - T movimum	Maximum gate current/voltage not to trigger is the maximum		0	mA	
DC gate voltage not to trigger	V _{GD}	$T_J = T_J \text{ maximum}$	value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.25		V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating temperature range	TJ		- 40 to 125	°C	
Maximum storage temperature range	T _{Stg}		- 40 to 150		
Maximum thermal resistance, junction to heatsink	В	DC operation single side cooled	0.073		
maximum thermal resistance, junction to heatsink	R _{thJ-hs}	DC operation double side cooled	0.031	K/W	
Manifestory the second control of the second	R _{thC-hs}	DC operation single side cooled	0.011		
Maximum thermal resistance, case to heatsink		DC operation double side cooled	0.006		
Mounting force, ± 10 %			14 700 (1500)	N (kg)	
Approximate weight			255	g	
Case style		See dimensions - link at the end of datasheet	TO-200AC	(B-PUK)	

∆R _{thJ-hs} CONDUCTION							
CONDUCTION ANGLE	SINUSOIDAL	SINUSOIDAL CONDUCTION		R CONDUCTION	TEST CONDITIONS	UNITS	
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS	
180°	0.009	0.009	0.006	0.006	$T_J = T_J$ maximum		
120°	0.011	0.011	0.011	0.011			
90°	0.014	0.014	0.015	0.015		K/W	
60°	0.020	0.020	0.021	0.021			
30°	0.036	0.036	0.036	0.036			

Note

• The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

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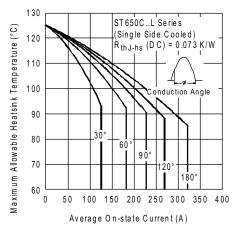


Fig. 1 - Current Ratings Characteristics

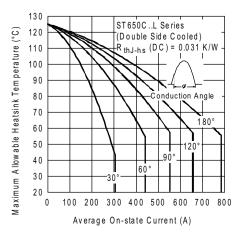


Fig. 2 - Current Ratings Characteristics

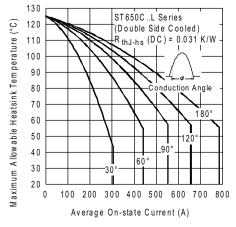


Fig. 3 - Current Ratings Characteristics

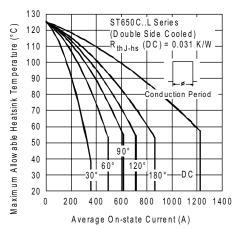


Fig. 4 - Current Ratings Characteristics

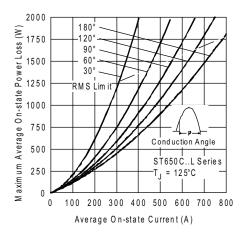


Fig. 5 - On-State Power Loss Characteristics

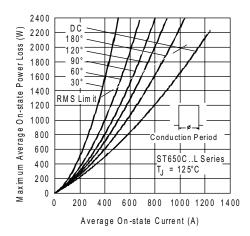


Fig. 6 - On-State Power Loss Characteristics



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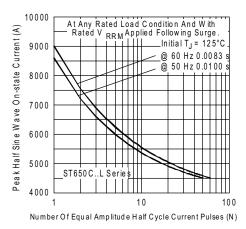


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

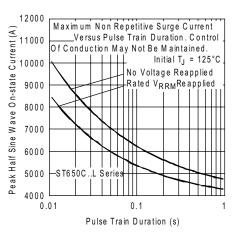


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

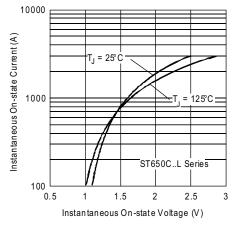


Fig. 9 - On-State Voltage Drop Characteristics

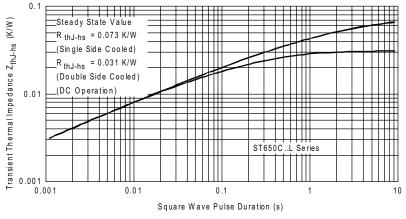


Fig. 10 - Thermal Impedance ZthJ-hs Characteristics

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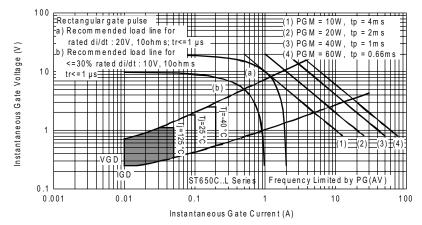
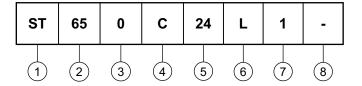


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



1 - Thyristor

Essential part number

3 - 0 = Converter grade

4 - C = Ceramic PUK

Voltage code x 100 = V_{RRM} (see Voltage Ratings table)

6 - L = PUK case TO-200AC (B-PUK)

7 - 0 = Eyelet terminals (gate and auxiliary cathode unsoldered leads)

1 = Fast-on terminals (gate and auxiliary cathode unsoldered leads)

2 = Eyelet terminals (gate and auxiliary cathode soldered leads)

3 = Fast-on terminals (gate and auxiliary cathode soldered leads)

8 - Critical dV/dt: • None = 500 V/µs (standard selection)

• L = 1000 V/µs (special selection)

LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95076			

www.vishay.com

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